## E-pHEMT MMIC

## Application

## Product Features

- Small size
- Higher Gain
- Higher linearity
- SOIC-8 SMD Type package
- Higher productivity
- Lower manufacturing cost
- -63dBc CSO 79 Channels @ +39dBmV/ch
- -64 dBc CTB 79 Channels @ $+39 \mathrm{dBmV} / \mathrm{ch}$
- -57 dBc XMD 79 Channels @+39dBmV/ch
- Low Noise Figure
- Low Noise Amplifier for

CATV, Satellite

- Cable Modem
- FTTH (G-PON, GE-PON)
- Optical node



## Description

AE617 is designed as low cost drive amplifiers for many applications including FTTH, CATV System.
This MMIC is based on Gallium Arsenide Enhancement Mode pHEMT which shows low current draw and very low noise.
The data in this spec sheet is valid only for 75 ohm application. 50 ohm data is in a separate spec sheet.

## Specifications

|  | PARAMETER |  | UNIT | MIN | TYP | MAX | Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Frequency |  | MHz | $50 \sim 1000$ |  |  |  |
|  | Gain |  | dB | 20 | 22 |  |  |
|  | Input Return Loss |  | dB |  | -22 |  |  |
|  | Output Return Loss |  | dB |  | -17 |  |  |
|  | Output IP3 |  | dBm | 38 | 41 |  | At $500 \mathrm{MHz} / 10 \mathrm{dBm} 2$ tone |
|  | 1 dB Compression Point |  | dBm | 25 | 28 |  | At 500 MHz |
|  | Noise Figure |  | dB |  | 2.3 | 3.5 |  |
|  | CSO | $30 \sim 870 \mathrm{MHz}$ | dBc |  | -63 | -58 | 79 channel, $+39 \mathrm{dBmV} / \mathrm{ch}$ |
| www.Datas | СТВ |  | dBc |  | -64 | -59 | 79 channel, $+39 \mathrm{dBmV} / \mathrm{ch}$ |
|  | XMOD |  | dBc |  | -57 | -52 | 79 channel, $+39 \mathrm{dBmV} / \mathrm{ch}$ |
|  | DC Current |  | mA |  | 260 |  | $\mathrm{Vdd}=8.0 \mathrm{~V}$ |

## NOTE

1. Test conditions unless otherwise noted. Test Freq $=500 \mathrm{MHz}, \mathrm{T}=25^{\circ} \mathrm{C}, \mathrm{Vdd}=8 \mathrm{~V}, 75 \Omega$ system
2. OIP3 measured with 2 tones at an output power of $+10 \mathrm{dBm} /$ tone separated by 1 MHz , Test Freq $=500 \mathrm{MHz}$

## Absolute Minimum and Maximum Ratings

| PARAMETER | UNIT | MIN | TYP | MAX |
| :---: | :---: | :---: | :---: | :---: |
| Device Voltage | VDC |  | +8 | +9 |
| Operating Temperature | ${ }^{\circ} \mathrm{C}$ | -40 |  | +85 |
| Storage Temperature | ${ }^{\circ} \mathrm{C}$ | -40 | +150 |  |

[^0]- All specifications may change without notice.
- Version 0.1


## E-pHEMT MMIC

© Application Circuit: $50 \mathrm{MHz} \sim 1000 \mathrm{MHz}$, 75ohm System

(O) Typical RF Performance: Vdd=8V, $\mathbf{I d s}=\mathbf{2 6 0 m A}, T=\mathbf{2 5}{ }^{\circ}$, $\mathbf{7 5 o h m}$ System

© Multi-Tone Test 79CH_FLAT@Output Power +39dBmV/Ch

|  |  | Level: +39dBmV Tilt: 79CH_FLAT |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| FRQ | XMD(NCTA) | CTB_RAW | CTB_COR | N-FLR | CSU_RAW | CSU_COR | CSU_FRQ | CSL_RAW | CSL_COR | CSL_FRQ |
| 55.25 | 57.4 | 64.9 | 64.9 | 84.6 | 83.6 | 87.9 | 56 | 72.5 | 72.8 | 54 |
| 211.25 | 57.9 | 65.4 | 65.4 | 85.2 | 76.4 | 77.1 | 212.5 | 72.2 | 72.4 | 209.99 |
| 331.25 | 58.2 | 64.5 | 64.5 | 84 | 70.6 | 70.8 | 332.49 | 71 | 71.2 | 329.99 |
| 445.25 | 58.2 | 65.4 | 65.4 | 84.9 | 67.8 | 67.8 | 446.49 | 75.1 | 75.6 | 444 |
| 547.25 | 58.8 | 66.9 | 67 | 82.8 | 63.1 | 63.1 | 548.5 | 73.7 | 74.2 | 546.49 |
| Min | 57.4 | 64.5 | 64.5 | 82.8 | 63.1 | 63.1 | 56 | 71 | 71.2 | 54 |
| Max | 58.8 | 66.9 | 67 | 85.2 | 83.6 | 87.9 | 548.5 | 75.1 | 75.6 | 546.49 |

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- rfsales@rfhic.com
- Version 0.1


## E-pHEMT MMIC

## Pin Description



| PIN No | Description |
| :---: | :---: |
| 1 | RF IN(2) |
| 5 | RF OUT(1) |
| 4 | RF IN(1) |
| 8 | RF OUT(2) |
| $2,3,6,7$ | N.C |
| Exposed slug | GND |

Package Dimensions (Type: SOIC-8)


| Unit $: \frac{\mathrm{mm}}{[\text { inch }]}$ | Tolerance $: \pm \frac{0.2}{.008}$ |
| :--- | :--- |


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